

ROHS

HALOGEN FREE

Hyperfast Rectifier, 30 A FRED Pt® G5



LINKS TO ADDITIONAL RESOURCES





PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V_R	1200 V					
V _F at I _F at 125 °C	1.7 V					
t _{rr}	32 ns					
T _J max.	175 °C					
Package	TO-220AC 2L					
Circuit configuration	Single					

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V _{RRM}		1200	V			
Average rectified forward current	I _{F(AV)}	T _C = 96 °C, D = 0.50	30				
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	240	Α			
Repetitive peak forward current	I _{FRM}	T _C = 96 °C, D = 0.50, f = 20 kHz	60				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	1200	-	-	.,		
Famous desirations	V _F	I _F = 30 A	-	1.9	2.5	V		
Forward voltage		I _F = 30 A, T _J = 125 °C	-	1.7	-			
Deverage legisage grament	I _R	$V_R = V_R$ rated	-	-	50	μA		
Reverse leakage current		T _J = 125 °C, V _R = V _R rated	-	-	500			
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	ı	8	-	nH		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I _F = 1.0 A, dI _F /dt = 100 A/μs, V _R = 30 V		-	32	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	113	-	ns	
		T _J = 125 °C		-	175	-		
Peak recovery current	1	T _J = 25 °C	$I_F = 20 \text{ A}$	-	17	-	А	
Feak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 600 A/μs V _R = 400 V	-	24	-		
Doverso vecessors charge	Q _{rr}	T _J = 25 °C		-	850	-	nC	
Reverse recovery charge		T _J = 125 °C		-	2150	-		
Poverse receivery time		T _J = 25 °C		-	85	-	ns A	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	132	-		
Dools was assent assert		T _J = 25 °C	I _F = 30 A	-	30	-		
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 1000 A/μs V _R = 800 V	-	43	-		
Reverse recovery charge	0	T _J = 25 °C		-	1350	-	nC	
	Q _{rr}	T _J = 125 °C		-	3215	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.1	°C/W		
Weight			-	2.0	-	g		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style TO-220AC 2L	E5TH3012TH					

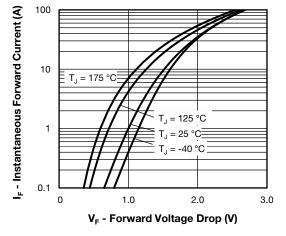


Fig. 1 - Typical Forward Voltage Drop Characteristics

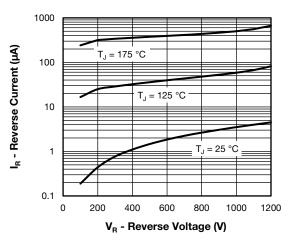


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



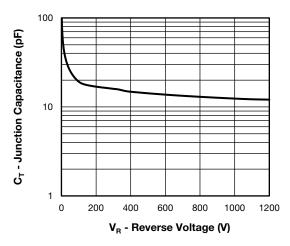


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

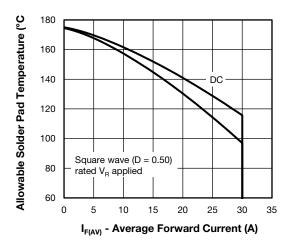


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

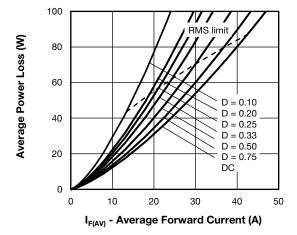


Fig. 5 - Forward Power Loss Characteristics

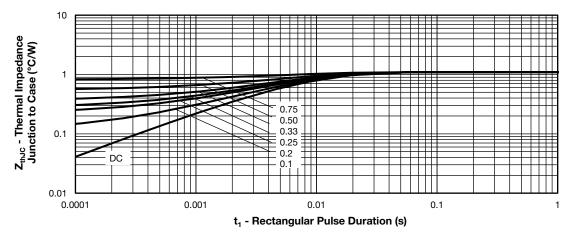
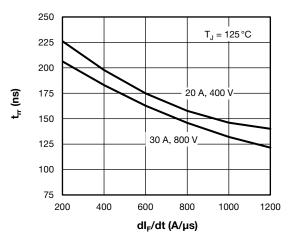


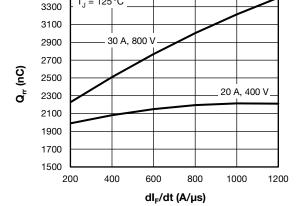
Fig. 6 - Thermal Impedance Z_{thJC} Characteristics



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T_J = 125 °C

Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt

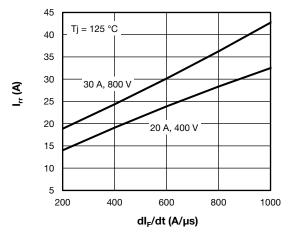


Fig. 9 - Typical Recovery Current vs. dl_F/dt



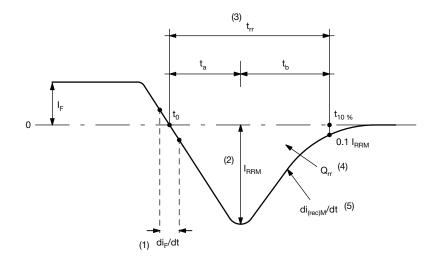


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}~Q_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

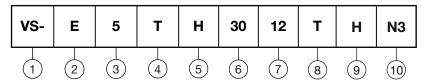
$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - E = single diode

3 - 5 = FRED generation 5

4 - Package: T = TO-220AC 2L

- H = hyperfast recovery

6 - Current rating (30 = 30 A)

7 - Voltage rating (12 = 1200 V)

8 - T = true 2 pin TO-220

9 - H = AEC-Q101 qualified

10 - Environmental digit:

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

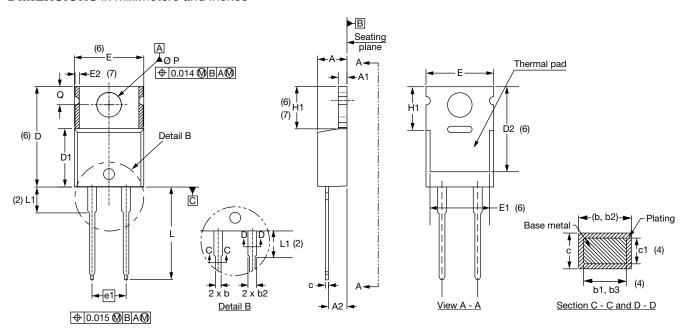
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5TH3012THN3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96069</u>					
Part marking information	www.vishay.com/doc?95391				
SPICE Model	www.vishay.com/doc?96926				



TO-220AC 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	INCHES	
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e1	4.88	5.28	0.192	0.208	
H1	5.84	6.86	0.230	0.270	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}$ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480"



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